

## TC74LVX86F, TC74LVX86FN, TC74LVX86FT

### Quad Exclusive OR Gate

The TC74LVX86F/ FN/ FT is a high-speed CMOS exclusive OR gate fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

The internal circuit includes an output buffer, which provides high noise immunity and stable output.

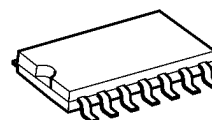
An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

### Features

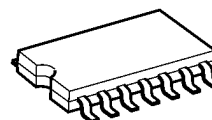
- High-speed:  $t_{pd} = 5.8 \text{ ns (typ.)}$  ( $V_{CC} = 3.3 \text{ V}$ )
- Low power dissipation:  $I_{CC} = 2 \mu\text{A (max)}$  ( $T_a = 25^\circ\text{C}$ )
- Input voltage level:  $V_{IL} = 0.8 \text{ V (max)}$  ( $V_{CC} = 3 \text{ V}$ )  
 $V_{IH} = 2.0 \text{ V (min)}$  ( $V_{CC} = 3 \text{ V}$ )
- Power-down protection provided on all inputs
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Low noise:  $V_{OLP} = 0.5 \text{ V (max)}$
- Pin and function compatible with 74HC86

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74LVX86F

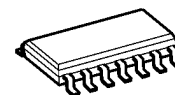


SOP14-P-300-1.27A



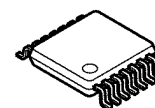
SOP14-P-300-1.27

TC74LVX86FN



SOL14-P-150-1.27

TC74LVX86FT

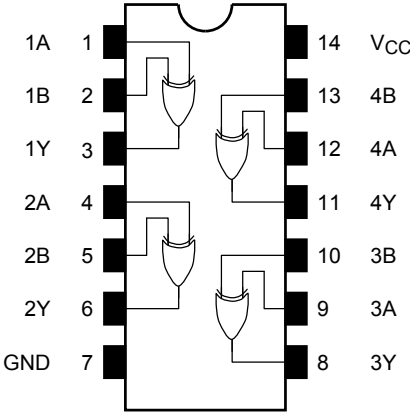


TSSOP14-P-0044-0.65A

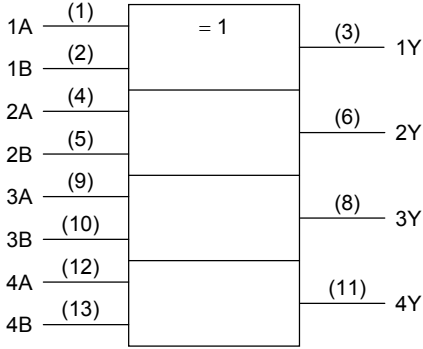
### Weight

|                      |                 |
|----------------------|-----------------|
| SOP14-P-300-1.27A    | : 0.18 g (typ.) |
| SOP14-P-300-1.27     | : 0.18 g (typ.) |
| SOL14-P-150-1.27     | : 0.12 g (typ.) |
| TSSOP14-P-0044-0.65A | : 0.06 g (typ.) |

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

| Inputs |   | Outputs |
|--------|---|---------|
| A      | B | Y       |
| L      | L | L       |
| L      | H | H       |
| H      | L | H       |
| H      | H | L       |

Absolute Maximum Ratings (Note)

| Characteristics             | Symbol    | Rating                 | Unit        |
|-----------------------------|-----------|------------------------|-------------|
| Supply voltage range        | $V_{CC}$  | -0.5 to 7.0            | V           |
| DC input voltage            | $V_{IN}$  | -0.5 to 7.0            | V           |
| DC output voltage           | $V_{OUT}$ | -0.5 to $V_{CC} + 0.5$ | V           |
| Input diode current         | $I_{IK}$  | -20                    | mA          |
| Output diode current        | $I_{OK}$  | $\pm 20$               | mA          |
| DC output current           | $I_{OUT}$ | $\pm 25$               | mA          |
| DC $V_{CC}$ /ground current | $I_{CC}$  | $\pm 50$               | mA          |
| Power dissipation           | $P_D$     | 180                    | mW          |
| Storage temperature         | $T_{stg}$ | -65 to 150             | $^{\circ}C$ |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

**Recommended Operating Conditions (Note)**

| Characteristics          | Symbol    | Rating        | Unit |
|--------------------------|-----------|---------------|------|
| Supply voltage           | $V_{CC}$  | 2.0 to 3.6    | V    |
| Input voltage            | $V_{IN}$  | 0 to 5.5      | V    |
| Output voltage           | $V_{OUT}$ | 0 to $V_{CC}$ | V    |
| Operating temperature    | $T_{opr}$ | -40 to 85     | °C   |
| Input rise and fall time | dt/dv     | 0 to 100      | ns/V |

Note: The recommended operating conditions are required to ensure the normal operation of the device.  
Unused inputs must be tied to either VCC or GND.

**Electrical Characteristics**
**DC Characteristics**

| Characteristics          |         | Symbol          | Test Condition  |                          | Ta = 25°C           |      |      | Ta = -40 to 85°C |      | Unit |     |
|--------------------------|---------|-----------------|---|--------------------------|---------------------|------|------|------------------|------|------|-----|
|                          |         |                 |   |                          | V <sub>CC</sub> (V) | Min  | Typ. | Max              | Min  |      | Max |
| Input voltage            | H-level | V <sub>IH</sub> | —   | 2.0                      | 1.5                 | —    | —    | 1.5              | —    | V    |     |
|                          |         |                 |   | 3.0                      | 2.0                 | —    | —    | 2.0              | —    |      |     |
|                          |         |                 |   | 3.6                      | 2.4                 | —    | —    | 2.4              | —    |      |     |
|                          | L-level | V <sub>IL</sub> | —   | 2.0                      | —                   | —    | 0.5  | —                | 0.5  |      |     |
|                          |         |                 |   | 3.0                      | —                   | —    | 0.8  | —                | 0.8  |      |     |
|                          |         |                 |   | 3.6                      | —                   | —    | 0.8  | —                | 0.8  |      |     |
| Output voltage           | H-level | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub> | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | 2.0  | —                | 1.9  | —    | V   |
|                          |         |                 |   | I <sub>OH</sub> = -50 μA | 3.0                 | 2.9  | 3.0  | —                | 2.9  | —    |     |
|                          |         |                 |   | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.58 | —    | —                | 2.48 | —    |     |
|                          | L-level | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub> | I <sub>OL</sub> = 50 μA  | 2.0                 | —    | 0    | 0.1              | —    | 0.1  |     |
|                          |         |                 |   | I <sub>OL</sub> = 50 μA  | 3.0                 | —    | 0    | 0.1              | —    | 0.1  |     |
|                          |         |                 |   | I <sub>OL</sub> = 4 mA   | 3.0                 | —    | —    | 0.36             | —    | 0.44 |     |
| Input leakage current    |         | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                          | 3.6                      | —                   | —    | ±0.1 | —                | ±1.0 | μA   |     |
| Quiescent supply current |         | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND                | 3.6                      | —                   | —    | 2.0  | —                | 20.0 | μA   |     |

## AC Characteristics (input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol            | Test Condition |                     |                     | Ta = 25°C |      |      | Ta = -40 to 85°C |      | Unit |
|-------------------------------|-------------------|----------------|---------------------|---------------------|-----------|------|------|------------------|------|------|
|                               |                   |                | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Typ. | Max  | Min              | Max  |      |
| Propagation delay time        | t <sub>pLH</sub>  | —              | 2.7                 | 15                  | —         | 7.5  | 14.5 | 1.0              | 17.5 | ns   |
|                               |                   |                |                     | 50                  | —         | 10.0 | 18.0 | 1.0              | 21.0 |      |
|                               | t <sub>pHL</sub>  |                | 3.3 ± 0.3           | 15                  | —         | 5.8  | 9.3  | 1.0              | 11.0 |      |
|                               |                   |                |                     | 50                  | —         | 8.3  | 12.8 | 1.0              | 14.5 |      |
| Output to output skew         | t <sub>osLH</sub> | (Note 1)       | 2.7                 | 50                  | —         | —    | 1.5  | —                | 1.5  | ns   |
|                               | t <sub>osHL</sub> |                | 3.3 ± 0.3           | 50                  | —         | —    | 1.5  | —                | 1.5  |      |
| Input capacitance             | C <sub>IN</sub>   | (Note 2)       |                     |                     | —         | 4    | 10   | —                | 10   | pF   |
| Power dissipation capacitance | C <sub>PD</sub>   | (Note 3)       |                     |                     | —         | 18   | —    | —                | —    | pF   |

Note 1: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Note 2: Parameter guaranteed by design.

Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

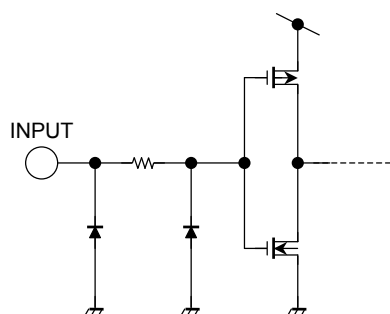
Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

## Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, C<sub>L</sub> = 50 pF)

| Characteristics  | Symbol           | Test Condition | V <sub>CC</sub> (V) | Typ. | Limit | Unit |
|--|------------------|----------------|---------------------|------|-------|------|
|  |                  |                |                     |      |       |      |
| Quiet output maximum dynamic V <sub>OL</sub>             | V <sub>OLP</sub> | —              | 3.3                 | 0.3  | 0.5   | V    |
| Quiet output minimum dynamic V <sub>OL</sub>             | V <sub>OLV</sub> | —              | 3.3                 | -0.3 | -0.5  | V    |
| Minimum high level dynamic input voltage V <sub>IH</sub> | V <sub>IHD</sub> | —              | 3.3                 | —    | 2.0   | V    |
| Maximum low level dynamic input voltage V <sub>IL</sub>  | V <sub>ILD</sub> | —              | 3.3                 | —    | 0.8   | V    |

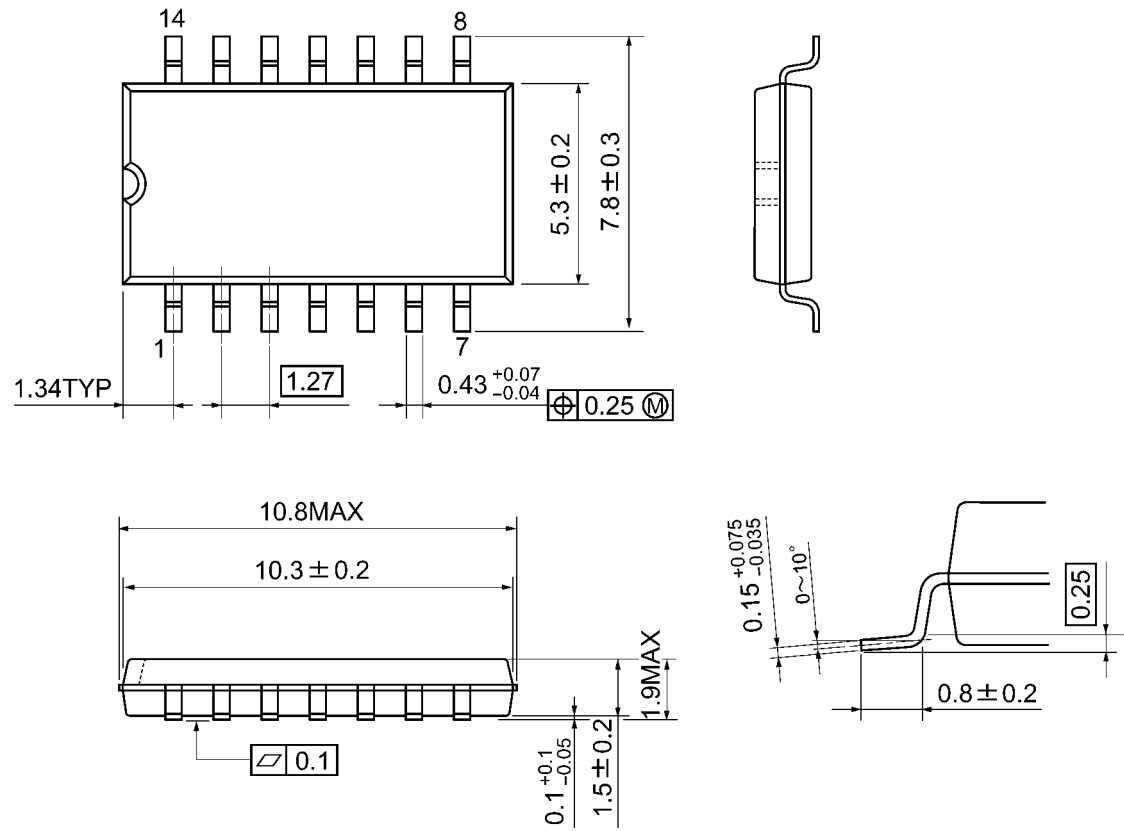
## Input Equivalent Circuit



Package Dimensions

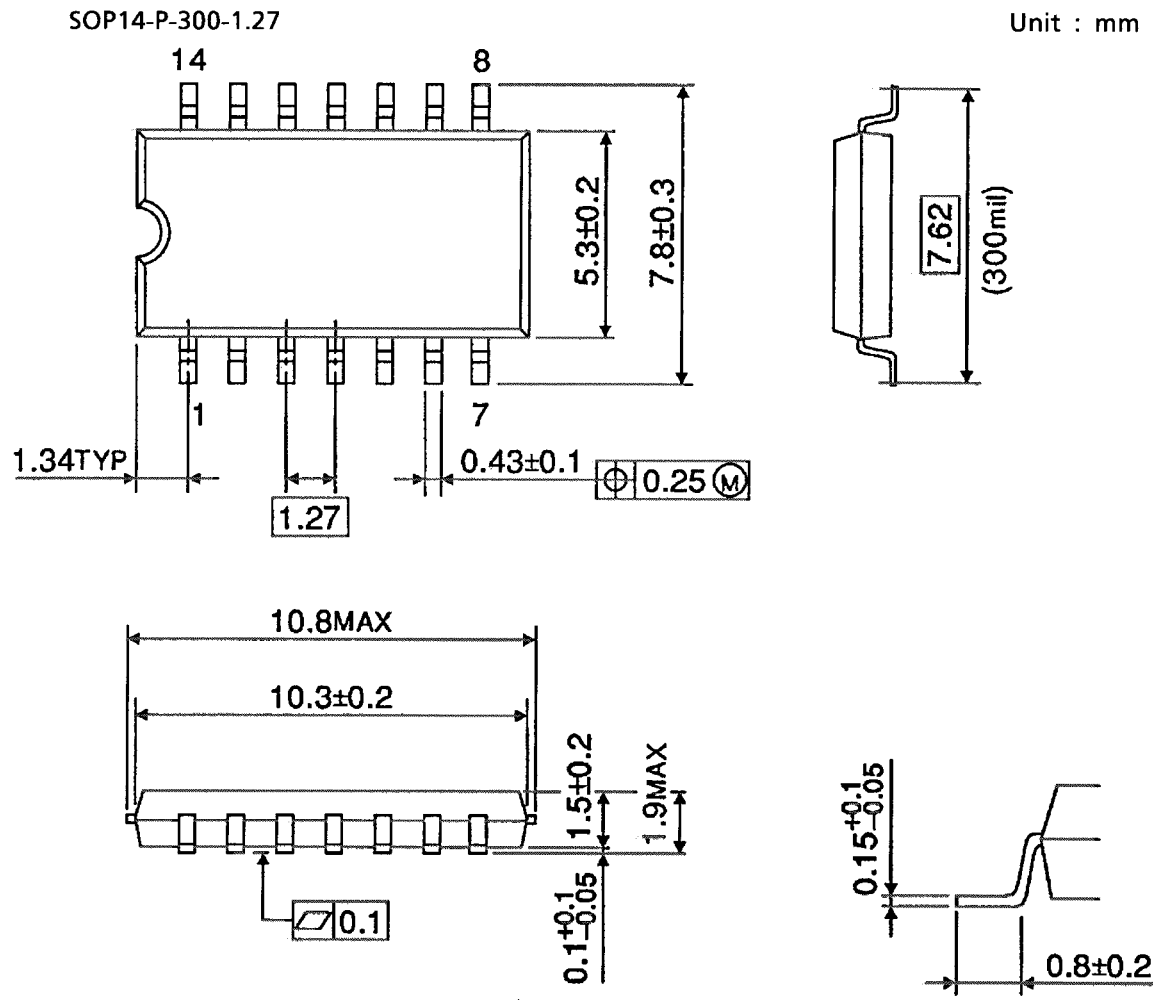
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

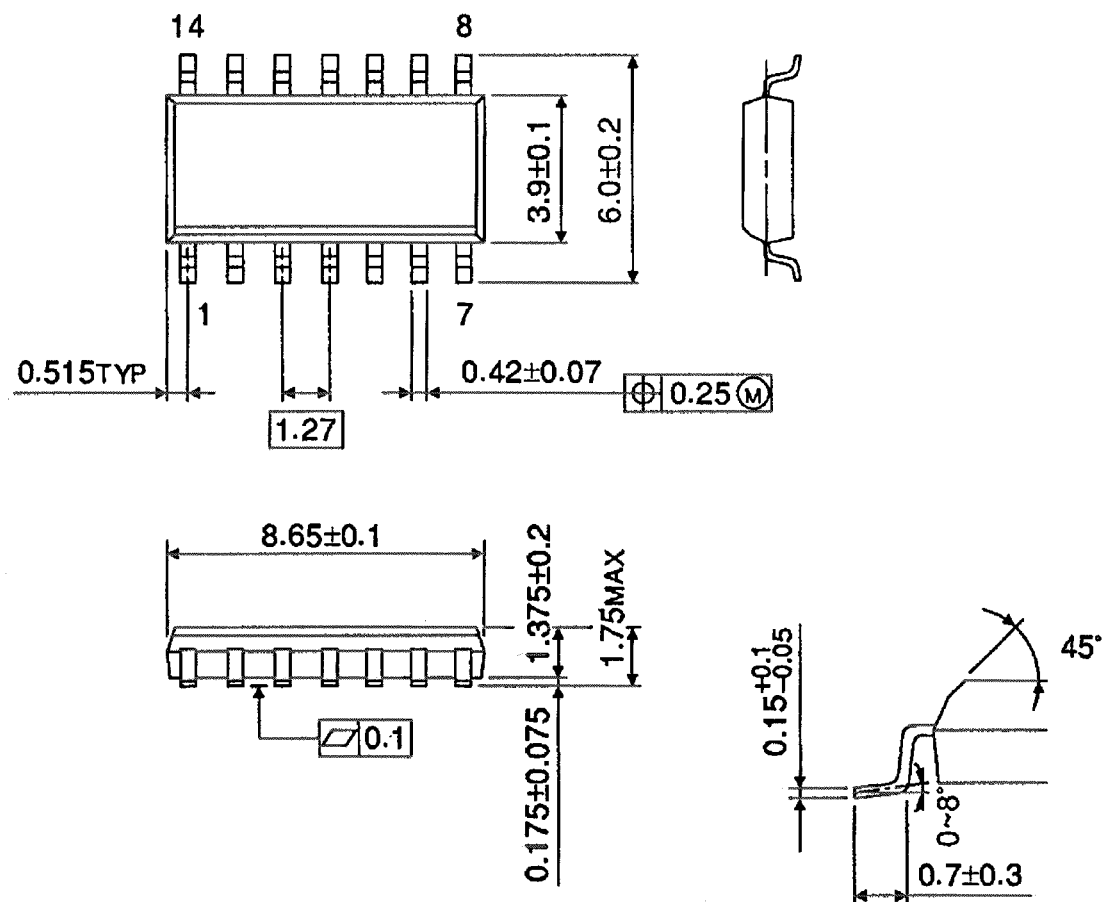


Weight: 0.18 g (typ.)

## Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



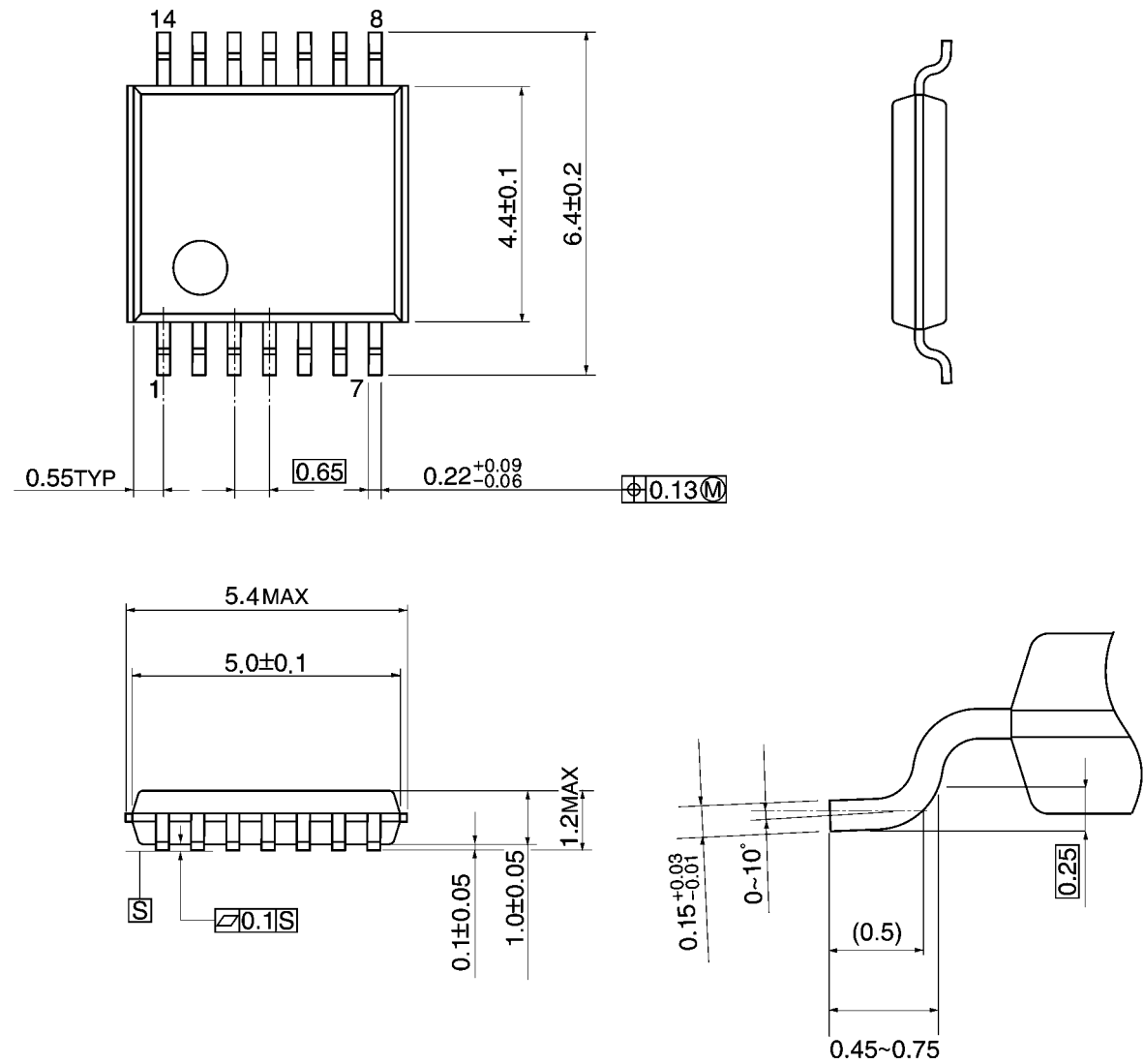
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)



**Note: Lead (Pb)-Free Packages****SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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